

产品规格书

Specification of products

产品名称：快速整流管模块

产品型号：MK110A4000V-T3

浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

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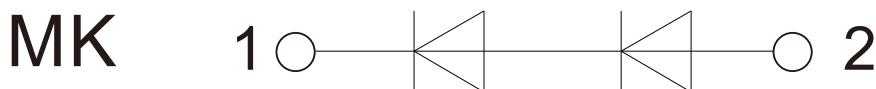
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拟制	审核	核准
林益龙	曹剑龙	宗瑞

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_J (°C)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean for ward current	180° half sine wave 50Hz Single side cooled, $T_C = 100^\circ C$	150			110	A
$I_{F(RMS)}$	RMS for ward current	Single side cooled, $T_C = 100^\circ C$	150			173	A
V_{RRM}	Repetitive peak reverse voltage	V_{RRM} tp=10ms $V_{RsM} = V_{DRM} \& V_{RRM} + 200V$	150		4000		V
I_{RRM}	Repetitive peak current	at V_{RRM}	150			15	mA
I_{FSM}	Surge for ward current	10ms half sine wave	150			1.50	KA
I^2t	I^2T for fusing coordination	$V_R = 0.6V_{RRM}$				34.4	$A^2s * 10^3$
V_{FO}	Threshold voltage		150			0.80	V
r_F	Forward slop resistance					1.74	$m\Omega$
V_{FM}	Peak for ward voltage	$I_{FM}=330A$	25			2.5	V
T_{rr}	Reverse Recovery Time		25			5	μs
$R_{th(j-c)}$	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.350	$^\circ C / W$
V_{iso}	Isolation voltage	50Hz, RM. S, t=1min, $I_{iso} = 1mA$ (max)		4500			V
F_m	Terminal connection torque(M5)				4.0		N.m
	Mounting torque(M6)				5.0		N.m
T_{Stg}	Stored temperature			-40		125	$^\circ C$
W_t	Weight				154		g
Outline							

OUTLINE DRAWING & CIRCUIT DIAGRAM



Rating and Characteristic

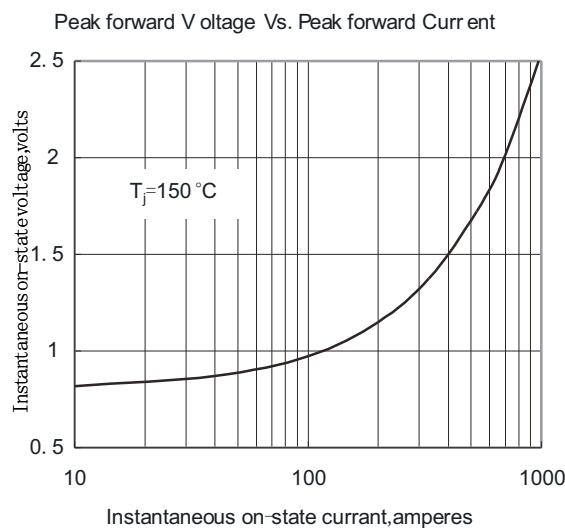


Fig. 1

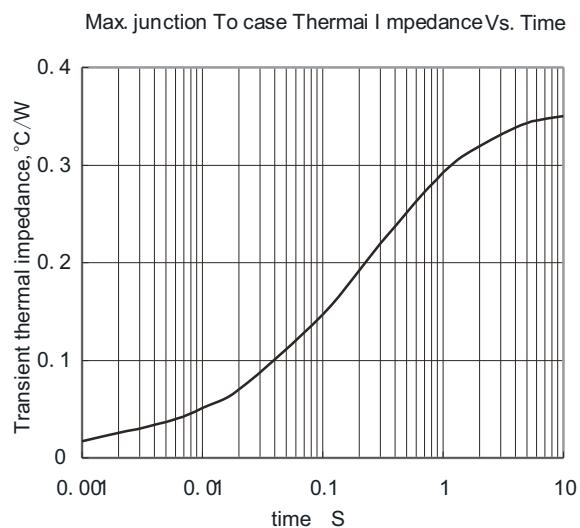


Fig. 2

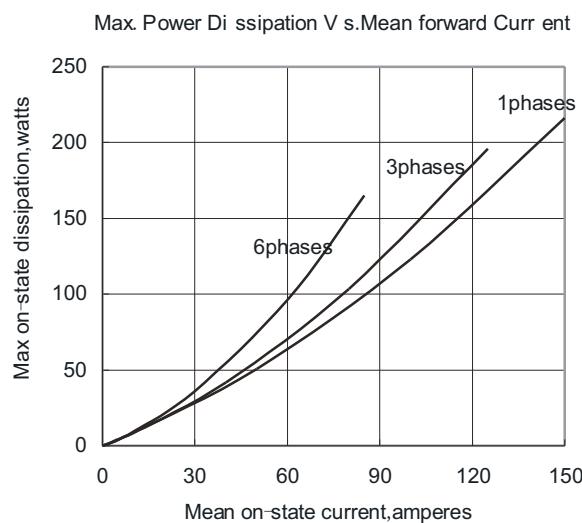


Fig. 3

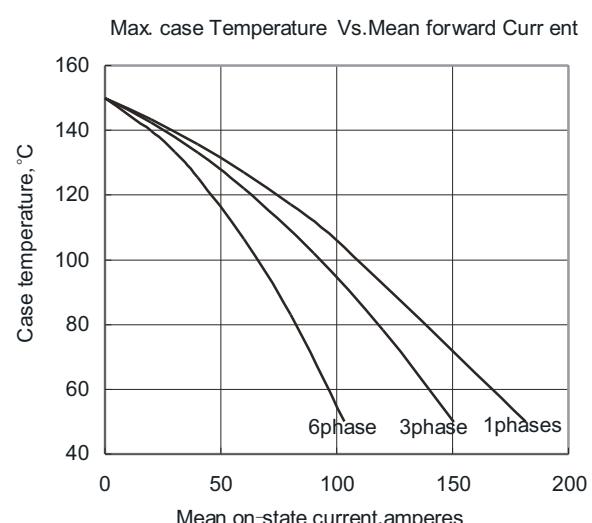


Fig. 4

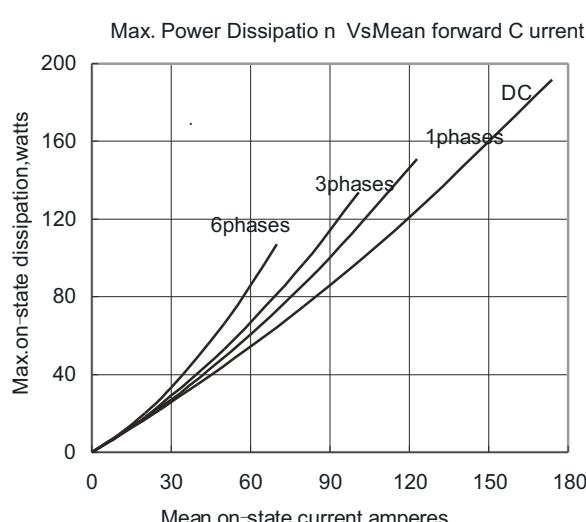


Fig. 5

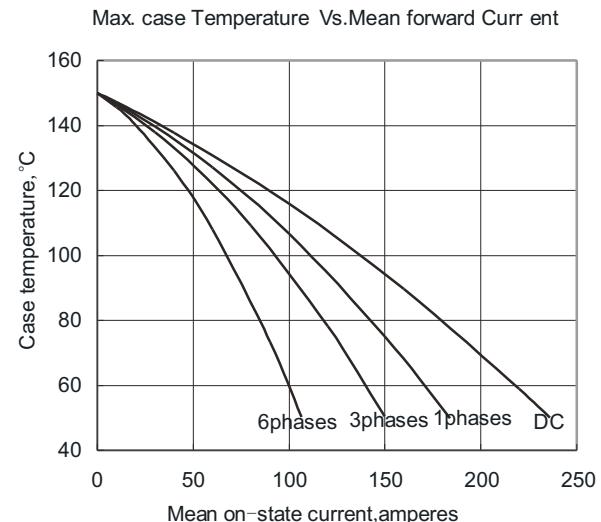


Fig. 6

Outside Dimension

